## **Mathias Mews**

## List of Publications by Year in Descending Order

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

32	1,214	15	<b>32</b>
papers	citations	h-index	g-index
32	1,394 ext. citations	5.2	4.33
ext. papers		avg, IF	L-index

#	Paper	IF	Citations
32	Energy-Level Alignment Tuning at Tetracene/c-Si Interfaces. <i>Journal of Physical Chemistry C</i> , <b>2020</b> , 124, 27867-27881	3.8	6
31	Three-Terminal Perovskite/Silicon Tandem Solar Cells with Top and Interdigitated Rear Contacts. <i>ACS Applied Energy Materials</i> , <b>2020</b> , 3, 1381-1392	6.1	31
30	Interface Molecular Engineering for Laminated Monolithic Perovskite/Silicon Tandem Solar Cells with 80.4% Fill Factor. <i>Advanced Functional Materials</i> , <b>2019</b> , 29, 1901476	15.6	27
29	Exploring co-sputtering of ZnO:Al and SiO2 for efficient electron-selective contacts on silicon solar cells. <i>Solar Energy Materials and Solar Cells</i> , <b>2019</b> , 194, 67-73	6.4	12
28	Toward Annealing-Stable Molybdenum-Oxide-Based Hole-Selective Contacts For Silicon Photovoltaics. <i>Solar Rrl</i> , <b>2018</b> , 2, 1700227	7.1	31
27	In-system photoelectron spectroscopy study of tin oxide layers produced from tetrakis(dimethylamino)tin by plasma enhanced atomic layer deposition. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , <b>2018</b> , 36, 02D401	2.9	6
26	Electronic structure of indium-tungsten-oxide alloys and their energy band alignment at the heterojunction to crystalline silicon. <i>Applied Physics Letters</i> , <b>2018</b> , 112, 011602	3.4	5
25	CsxFA1\(\text{QPb}(\) 1\(\text{QBry})3\) Perovskite Compositions: the Appearance of Wrinkled Morphology and its Impact on Solar Cell Performance. <i>Journal of Physical Chemistry C</i> , <b>2018</b> , 122, 17123-17135	3.8	31
24	Crystalline silicon solar cells with tetracene interlayers: the path to silicon-singlet fission heterojunction devices. <i>Materials Horizons</i> , <b>2018</b> , 5, 1065-1075	14.4	58
24		14.4	58
	heterojunction devices. <i>Materials Horizons</i> , <b>2018</b> , 5, 1065-1075  Interdigitated back contact silicon heterojunction solar cells: Towards an industrially applicable	14.4 4.9	
23	heterojunction devices. <i>Materials Horizons</i> , <b>2018</b> , 5, 1065-1075  Interdigitated back contact silicon heterojunction solar cells: Towards an industrially applicable structuring method <b>2018</b> ,  Potential of PEDOT:PSS as a hole selective front contact for silicon heterojunction solar cells.		3
23	heterojunction devices. <i>Materials Horizons</i> , <b>2018</b> , 5, 1065-1075  Interdigitated back contact silicon heterojunction solar cells: Towards an industrially applicable structuring method <b>2018</b> ,  Potential of PEDOT:PSS as a hole selective front contact for silicon heterojunction solar cells. <i>Scientific Reports</i> , <b>2017</b> , 7, 2170  Optimized Metallization for Interdigitated Back Contact Silicon Heterojunction Solar Cells. <i>Solar Rrl</i> ,	4.9	3 49
23 22 21	Interdigitated back contact silicon heterojunction solar cells: Towards an industrially applicable structuring method 2018,  Potential of PEDOT:PSS as a hole selective front contact for silicon heterojunction solar cells. Scientific Reports, 2017, 7, 2170  Optimized Metallization for Interdigitated Back Contact Silicon Heterojunction Solar Cells. Solar Rrl, 2017, 1, 1700021  Aluminium metallisation for interdigitated back-contact silicon heterojunction solar cells. Japanese	4·9 7·1	3 49
23 22 21 20	Interdigitated back contact silicon heterojunction solar cells: Towards an industrially applicable structuring method 2018,  Potential of PEDOT:PSS as a hole selective front contact for silicon heterojunction solar cells. Scientific Reports, 2017, 7, 2170  Optimized Metallization for Interdigitated Back Contact Silicon Heterojunction Solar Cells. Solar Rrl, 2017, 1, 1700021  Aluminium metallisation for interdigitated back-contact silicon heterojunction solar cells. Japanese Journal of Applied Physics, 2017, 56, 08MB22  Sputtered Tungsten Oxide as Hole Contact for Silicon Heterojunction Solar Cells. IEEE Journal of	4.9 7.1 1.4	3 49 9
23 22 21 20	Interdigitated back contact silicon heterojunction solar cells: Towards an industrially applicable structuring method 2018,  Potential of PEDOT:PSS as a hole selective front contact for silicon heterojunction solar cells. Scientific Reports, 2017, 7, 2170  Optimized Metallization for Interdigitated Back Contact Silicon Heterojunction Solar Cells. Solar Rrl, 2017, 1, 1700021  Aluminium metallisation for interdigitated back-contact silicon heterojunction solar cells. Japanese Journal of Applied Physics, 2017, 56, 08MB22  Sputtered Tungsten Oxide as Hole Contact for Silicon Heterojunction Solar Cells. IEEE Journal of Photovoltaics, 2017, 7, 1209-1215  Oxygen vacancies in tungsten oxide and their influence on tungsten oxide/silicon heterojunction	4.9 7.1 1.4 3.7	3 49 9 4 33

## LIST OF PUBLICATIONS

15	Electrochemically deposited ZnO nanostructured array films as antireflection coating on silicon heterojunction solar cells. <i>Physica Status Solidi (A) Applications and Materials Science</i> , <b>2015</b> , 212, 166-170	o <sup>1.6</sup>	6	
14	Valence band alignment and hole transport in amorphous/crystalline silicon heterojunction solar cells. <i>Applied Physics Letters</i> , <b>2015</b> , 107, 013902	3.4	39	
13	Valence band offset in heterojunctions between crystalline silicon and amorphous silicon (sub)oxides (a-SiOx:H, 0 Applied Physics Letters, <b>2015</b> , 106, 031601	3.4	29	
12	Hydrogen Plasma Treatments of Amorphous/Crystalline Silicon Heterojunctions. <i>Energy Procedia</i> , <b>2014</b> , 55, 827-833	2.3	8	
11	Over 20% conversion efficiency on silicon heterojunction solar cells by IPA-free substrate texturization. <i>Applied Surface Science</i> , <b>2014</b> , 301, 56-62	6.7	34	
10	Optical and structural properties of electrochemically deposited ZnO nanorod arrays suitable for improvement of the light harvesting in thin film solar cells. <i>Journal of Physics: Conference Series</i> , <b>2014</b> , 559, 012018	0.3	1	
9	Evolution of the Charge Carrier Lifetime Characteristics in Crystalline Silicon Wafers During Processing of Heterojunction Solar Cells. <i>Energy Procedia</i> , <b>2014</b> , 55, 219-228	2.3	8	
8	Solution-processed amorphous silicon surface passivation layers. <i>Applied Physics Letters</i> , <b>2014</b> , 105, 122	1314	10	
7	Amorphous/crystalline silicon heterojunction solar cells with black silicon texture. <i>Physica Status Solidi - Rapid Research Letters</i> , <b>2014</b> , 8, 831-835	2.5	10	
6	Comparison of TMB and B2H6 as Precursors for Emitter Doping in High Efficiency Silicon Hetero Junction Solar Cells. <i>Energy Procedia</i> , <b>2014</b> , 60, 123-128	2.3	12	
5	Approach for a Simplified Fabrication Process for IBC-SHJ Solar Cells with High Fill Factors. <i>Energy Procedia</i> , <b>2013</b> , 38, 732-736	2.3	8	
4	Amorphous Silicon Passivation of Surfaces Promoting Epitaxy. <i>Energy Procedia</i> , <b>2013</b> , 38, 855-861	2.3	10	
3	Passivation of Textured Silicon Wafers:Influence of Pyramid Size Distribution, a-Si:H Deposition Temperature, and Post-treatment. <i>Energy Procedia</i> , <b>2013</b> , 38, 881-889	2.3	27	
2	Hydrogen plasma treatments for passivation of amorphous-crystalline silicon-heterojunctions on surfaces promoting epitaxy. <i>Applied Physics Letters</i> , <b>2013</b> , 102, 122106	3.4	115	
1	AgGaSe2 thin films grown by chemical close-spaced vapor transport for photovoltaic applications:	1.8	6	